



# Transmission Laser

Modules

## **Key**Features

7-pin Low Profile package with GPO connector RF input

High frequency RF connector package with  $50\Omega$  RF impedance

InGaAsP monolithically integrated DFB laser and modulator chip

Low drive voltage (≤ 2 Vpp)

RoHs Compliant

### **Applications**

Metro SONET/SDH and D-WDM equipment

STM-64 (Long-Haul) and OC-192 (Intermediate-Reach) 300-pin MSA SFF Transponder

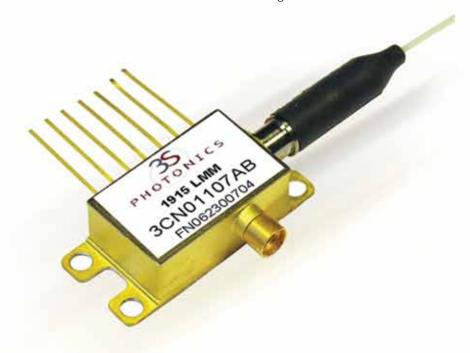
10 GbE 300-pin MSA Transponder

## **1915 LMM WDM LP**

# WDM - 800 ps/nm application - 10 Gbit/s digital Laser Module with integrated electro-absorption Modulator

The 1915 LMM contains a 3SPGroup DFB laser with monolithically integrated electro-absorption modulator (EA-ILM).

The modulation voltage is applied to the modulator section while the DFB laser operates CW. Without the complexity of LiNbO3 external modulators, the 1915 LMM is dedicated to STM64/OC-192 bit rate with reduced size and reduced cost. This device allows 10.7 Gbit/s data transmission with an extinction ratio higher than 10 dB and less than 2 V modulation voltage.



#### For moreInfo

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# OPTICAL CHARACTERISTICS

| Parameters                                  | Symb  | Conditions  | Min     | Max     | Units |
|---|-------|---|---------|---------|-------|
| Operating case temperature                  | Tc    |   | -5      | 75      | °C    |
| Threshold current                           | Ith   | CW  | 5       | 35      | mA    |
| Operating current                           | lf    | CW  | 70      | 100     | mA    |
| Optical output power (EOL)                  | Pave  | If, Vmod, [1], [2]  | -1      | 2       | dBm   |
| Tracking error                              | TE    | measurement @ -5 & 75 °C<br>are set @ constant IF (25 C), See [3] | -0.5    | +0.5    | dB    |
| Laser forward voltage                       | Vf    | CW, If, Vbias= 0V   |         | 2       | ٧     |
| ON state voltage                            | Von   | See [1] -   |         | 0       | V     |
| Modulator bias voltage                      | Vbias | See [1]   |         |         | V     |
| Modulator drive voltage                     | Vmod  | See [1]   |         | 2       | V     |
| Dynamic extinction ratio                    | DER   | If, [1], [2]  | 10      |         | dB    |
| Emission wavelength                         | λ     |   | 1528.77 | 1563.86 | nm    |
| Laser Chip temperature range For Tunability | Twave | See [4]   | 25      | 40      | °C    |
| Side mode suppression                       | SMSR  | See [1]   | 40      |         | DB    |
| Relative intensity noise                    | RIN   | 100 MHz to 9 GHz, @ Pave  |         | -130    | dB/Hz |
| Cut off frequency                           | S21   | - 3 dB, Vbias @ If  | 9       |         | GHz   |
| RF return loss                              | S11   | DC to 7 GHz   | 10      |         | DB    |
|   | S11   | 7 to 10 GHz   |         | 7       | DB    |
| Dispersion penalty                          | λS    | See [1], [2]  |         | 2       | DB    |
| Rise time / Fall time                       | Tr/Tf | See [1], 10%, 90%   |         | 45      | ps    |
| Monitor diode current                       | lm /  | If, V = - 5 V   | 20      | 1500    | μA    |
| Monitor diode dark current                  | ld    | If, V = - 5 V   |         | 0.1     | μΑ    |
| Monitor diode capacitance                   | Cm    | @ 1MHz, V = -5 V  |         | 15      | pF    |
| TEC current                                 | lt    | ΔT= 50°C, If+20% (EOL), Vbias= - 1V                               |         | 1.3     | A     |
| TEC voltage                                 | Vt    | $\Delta T = 50^{\circ}C$ , If +20% (EOL), Vbias = -1V             |         | 2.5     | V     |
| Thermistor resistance                       | RTH   | Tsubmount= 25°C   | 9.5     | 10.5    | kΩ    |
| Thermistor β coefficient                    | β     | Tsubmount= 25°C   | 3800    | 4000    | K     |

Notes : All limits start of life Tcase in the range [-5°C; 75°C], Tsubmount= Twave , monitor bias= -5V, unless otherwise stated

[1] BER= 10<sup>-10</sup>; 10.7 Gbit/s modulation; 231-1 PRBS;NZR line code.

**[2]** 1600 ps/nm dispersion assuming fiber with an average dispersion of 18 ps/nm/km @ 1550 nm.

[3] TE = Max { $|[P(75^{\circ}C)-P(25^{\circ}C)]/P(25^{\circ}C)|$ ;  $|[P(-5^{\circ}C)-P(25^{\circ}C)]/P(25^{\circ}C)|$ }.

[4] For WDM applications Tsubmount= Twave. Twave is the chip temperature required to meet target wavelength (See table 3).

# Absolute Maximum Ratings

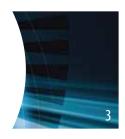
Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

| Parameters  | Min  | Max  | Unit |
|---|------|------|------|
| Operating case temperature                              | -5   | 75   | °C   |
| Storage temperature                                     | - 40 | 85   | °C   |
| CW optical output power                                 |      | 10   | dBm  |
| Laser forward current                                   |      | 150  | mA   |
| Laser reverse voltage                                   |      | 2    | V    |
| Modulator forward voltage                               |      | 1    | V    |
| Modulator reverse voltage                               |      | 5    | V    |
| Photodiode forward current                              |      | 1    | mA   |
| Photodiode reverse voltage                              |      | 20   | V    |
| TEC voltage   |      | 2.8  | V    |
| TEC current   |      | 1.4  | Α    |
| ESD applied on PIN detector (pid 4&5, human body model) |      | 100  | V    |
| ESD applied on other pins (humand body model)           |      | 2000 | V    |
| Lead soldering time (at 260°C)                          |      | 10   | S    |
| Fiber bend radius                                       | 25   |      | mm   |
| Packing mounting screw torque                           |      | 0.2  | nm   |

## 1915 LMM WDM LP

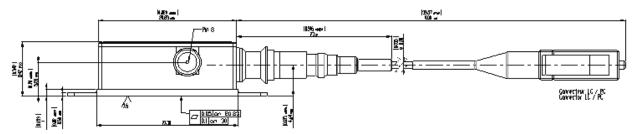
WDM - 800 ps/nm application - 10 Gbit/s digital Laser Module with integrated electro-absorption Modulator

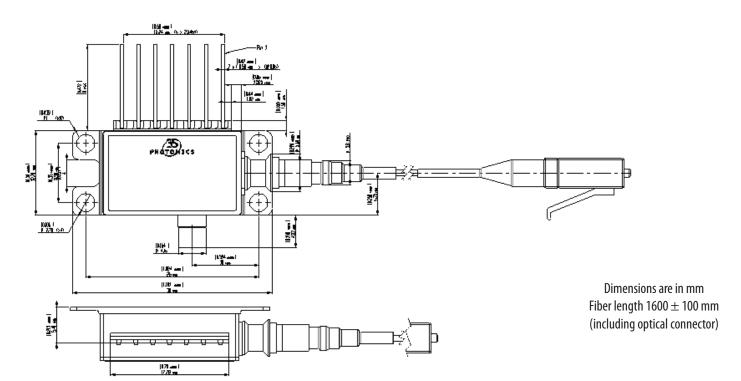




## Mechanical

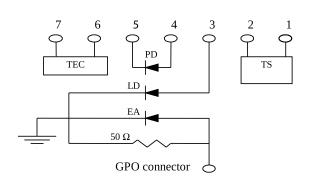
#### **Details**





#### Pin Out

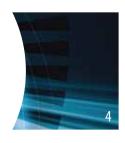
| N° | Description               |
|----|---------------------------|
| 1  | Thermistor                |
| 2  | Thermistor                |
| 3  | Laser DC bias (+)         |
| 4  | Photodetector Anode (-)   |
| 5  | Photodetector Cathode (+) |
| 6  | TEC (+)                   |
| 7  | TEC (-)                   |



## 1915 LMM WDM LP

WDM - 800 ps/nm application - 10 Gbit/s digital Laser Module with integrated electro-absorption Modulator





#### Shipment packing

Each device is individually packed in an anti-static container and in such a manner as to prevent damage in transit.

## The packing shall include the following information:

3S Photonics logo

Product family name: 1915

LMM

Product code: 3CN number (see Ordering information

section)

Serial number

Hazard warning label (ESD) Laser Safety Class Label

Laser Safety

#### **Information**

Take appropriate precautions to prevent undue exposure to naked eye.

This product is classified Class 1M Laser Product according to IEC-60825-1: edition2.

All versions are Class IIIB laser products per 21 CFR 1040-10 Laser. Safety requirements under accession number 0120546-00.



#### Qualification, Reliability and Standards

3SPGroup policy for all products is to carry out a complete qualification program. This qualification is based on manufacturers' qualification in agreement with Telcordia GR-468-Core (Generic Reliability Assurance Requirements for Optoelectronic Devtices Used In Telecommunications Equipment - Central Office Level), MIL STD 883E (Test method and procedures for microelectronics) and following the standards ITU-T G652 and G-691. All products pass strict tests before shipping. Failure criteria are defined during the product qualification process.

#### Device marking

The device shall be legibly and permanently marked with the following

information: 3S Photonics logo

Product family name: 1915 LMM

Product code: 3CN number (see Ordering information section)

Serial number

#### Deliverable data

The following data shall be supplied with each device:

L(I) / V(I) / Im(I) curves Values for Vmod, Von (On-state voltage [0 data]), Vbias (bias voltage), S0 (received optical power without fiber), SMSR, ITH, It, Vt, I and Pave for If DER and dispersion penalty (DS)

Plot of SER vs Vmod over the range 0 V to -3 V @ If , Tc= 25 °C and Tsubmount= Twave

#### **Handling**

This product is sensitive to electrostatic discharge and should not be handled except at a static free workstation. Take precautions to prevent ESD; use wrist straps, grounded work surfaces and recognised anti-static techniques when handling the product. Handle the laser module by its package only, never hold it by its pigtail.



Care should be taken to avoid supply transient and over voltage. Over voltage above the maximum specified in absolute maximum rating section may cause permanent damage to the device.

## 1915 LMM WDM LP

WDM - 800 ps/nm application - 10 Gbit/s digital **Laser Module with integrated electro-absorption Modulator** 





#### **ORDERING** INFORMATION

| Application | Part number | Electrical<br>Connector | Optical<br>Connector |  |
|-------------|-------------|-------------------------|----------------------|--|
| WDM         | 3CN01107##  | GPO type                | LC/PC                |  |

## defines the wavelength according to the Table 3.

Table 3

| λ<br>(nm) | THz    | Code<br>## | λ<br>(nm) | THz    | Code<br>## |
|-----------|--------|------------|-----------|--------|------------|
| 1528,77   | 196,10 | BM         | 1546,92   | 193,80 | DK         |
| 1529,55   | 196,00 | BP         | 1547,72   | 193,70 | DM         |
| 1530,33   | 195,90 | BR         | 1548,51   | 193,60 | DP         |
| 1531,12   | 195,80 | BT         | 1549,32   | 193,50 | DR         |
| 1531,90   | 195,70 | BV         | 1550,12   | 193,40 | DT         |
| 1532,68   | 195,60 | ВХ         | 1550,92   | 193,30 | DV         |
| 1533,47   | 195,50 | BZ         | 1551,72   | 193,20 | DX         |
| 1534,25   | 195,40 | СВ         | 1552,52   | 193,10 | DZ         |
| 1535,04   | 195,30 | CD         | 1553,33   | 193,00 | EB         |
| 1535,82   | 195,20 | CF         | 1554,12   | 192,90 | ED         |
| 1536,61   | 195,10 | CH         | 1554,94   | 192,80 | EF         |
| 1537,40   | 195,00 | CK         | 1555,75   | 192,70 | EH         |
| 1538,19   | 194,90 | CM         | 1556,55   | 192,60 | EK         |
| 1538,98   | 194,80 | CP         | 1557,36   | 192,50 | EM         |
| 1539,77   | 194,70 | CR         | 1558,17   | 192,40 | EP         |
| 1540,56   | 194,60 | CT         | 1558,98   | 192,30 | ER         |
| 1541,35   | 194,50 | CV         | 1559,79   | 192,20 | ET         |
| 1542,14   | 194,40 | CX         | 1560,61   | 192,10 | EV         |
| 1542,94   | 194,30 | CZ         | 1561,42   | 192,00 | EX         |
| 1543,73   | 194,20 | DB         | 1562,23   | 191,90 | EZ         |
| 1544,53   | 194,10 | DD         | 1563,05   | 191,80 | FB         |
| 1545,32   | 194,00 | DF         | 1563,86   | 191,70 | FD         |
| 1546,12   | 193,90 | DH         | JAPAN N   |        |            |

All wavelengths referenced to vacuum, Twave for WDM applications.

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ORDERING INFO

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